



SANYO Semiconductors

DATA SHEET

2SC5245A

NPN Epitaxial Planar Silicon Transistor

UHF to S-Band Low-Noise Amplifier OSC Applications

Features

- Low-noise : NF=0.9dB typ (f=1GHz).
: NF=1.4dB typ (f=1.5GHz).
- High gain : $|S_{21e}|^2=10\text{dB}$ typ (f=1.5GHz).
- High cut-off frequency : $f_T=8\text{GHz}$ typ.
- Low-voltage, low-current operation ($V_{CE}=1\text{V}$, $I_C=1\text{mA}$).
: $f_T=3.5\text{GHz}$ typ.
: $|S_{21e}|^2=5.5\text{dB}$ typ (f=1.5GHz).

Specifications

Absolute Maximum Ratings at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		20	V
Collector-to-Emitter Voltage	V_{CEO}		10	V
Emitter-to-Base Voltage	V_{EBO}		1.5	V
Collector Current	I_C		30	mA
Collector Dissipation	P_C		150	mW
Junction Temperature	T_j		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

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Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=10V, I_E=0A$			1.0	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=1V, I_C=0A$			10	μA
DC Current Gain	h_{FE}	$V_{CE}=5V, I_C=10mA$	60*		270*	
Gain-Bandwidth Product	f_T1	$V_{CE}=5V, I_C=10mA$	5	8		GHz
	f_T2	$V_{CE}=1V, I_C=1mA$		3.5		GHz
Output Capacitance	C_{ob}	$V_{CB}=10V, f=1MHz$		0.45	0.7	pF
Reverse Transfer Capacitance	C_{re}	$V_{CB}=10V, f=1MHz$		0.30		pF
Forward Transfer Gain	$ S_{21e} ^{21}$	$V_{CE}=5V, I_C=10mA, f=1.5GHz$	8	10		dB
	$ S_{21e} ^{22}$	$V_{CE}=1V, I_C=1mA, f=1.5GHz$		5.5		dB
Noise Figure	NF1	$V_{CE}=5V, I_C=5mA, f=1.5GHz$		1.4	3.0	dB
	NF2	$V_{CE}=2V, I_C=3mA, f=1GHz$		0.9		dB

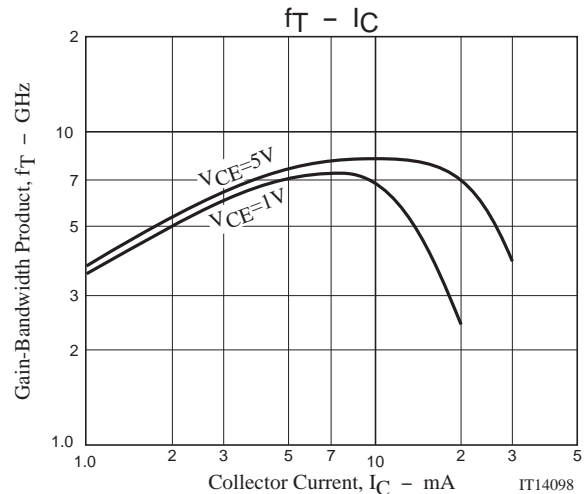
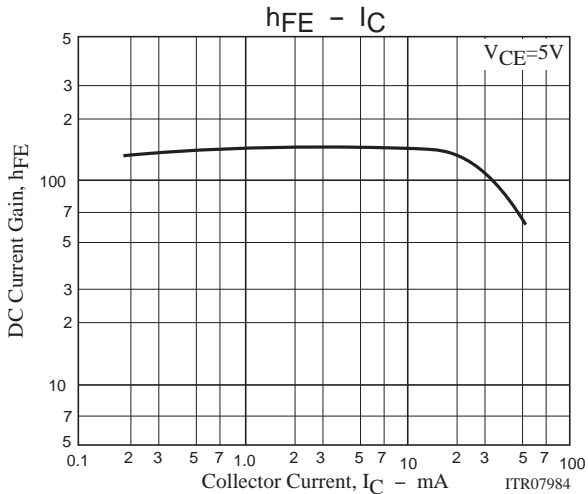
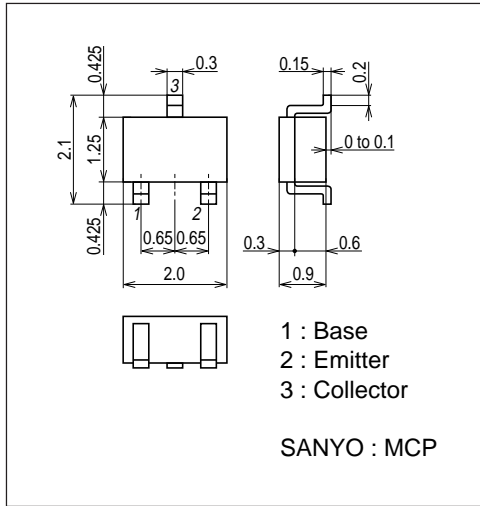
* : The 2SC5245A is classified by 10mA h_{FE} as follows :

Marking	MN3	MN4	MN5
Rank	3	4	5
h_{FE}	60 to 120	90 to 180	135 to 270

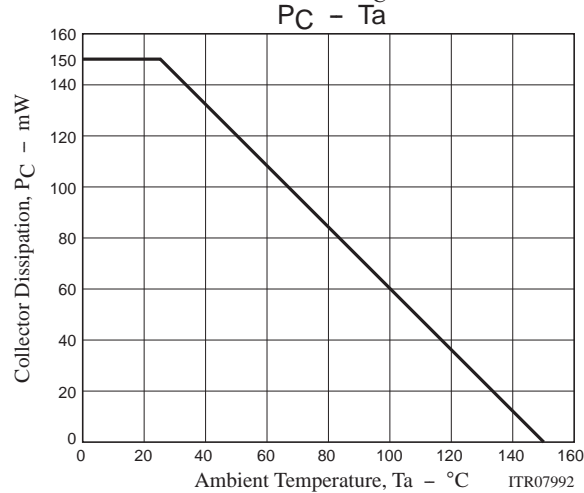
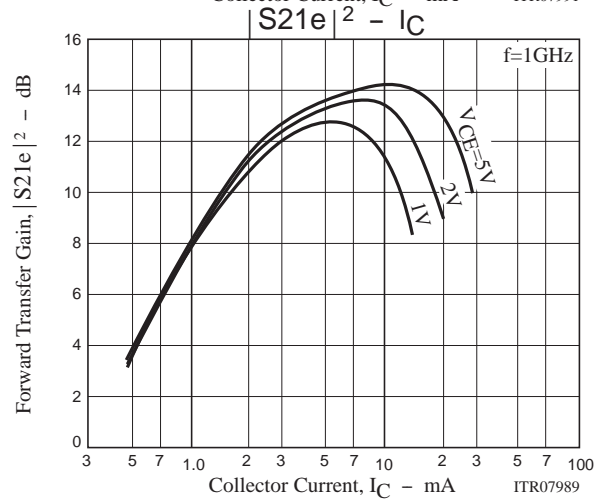
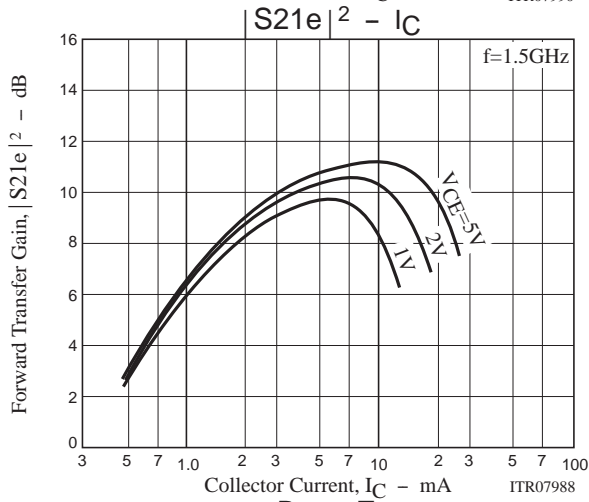
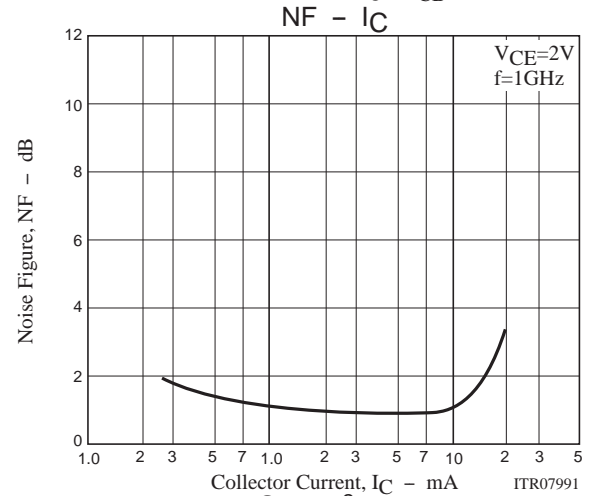
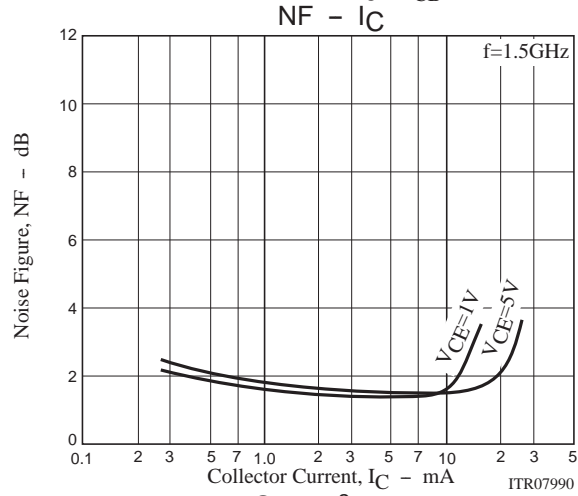
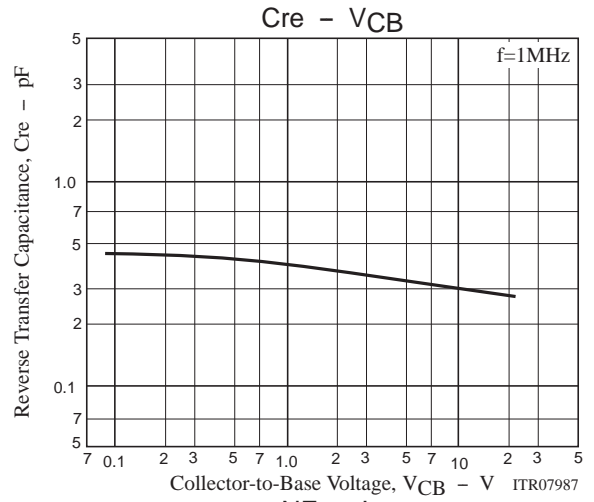
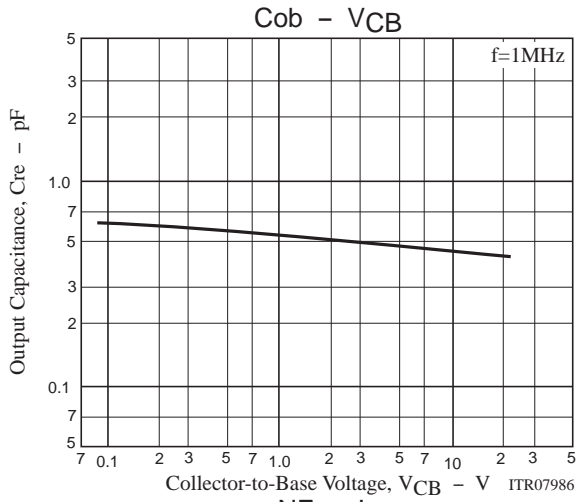
Package Dimensions

unit : mm (typ)

7023-009



2SC5245A

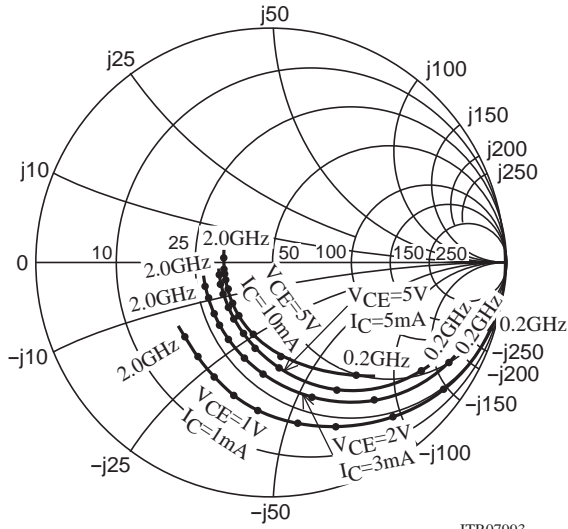


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S Parameters

S11e

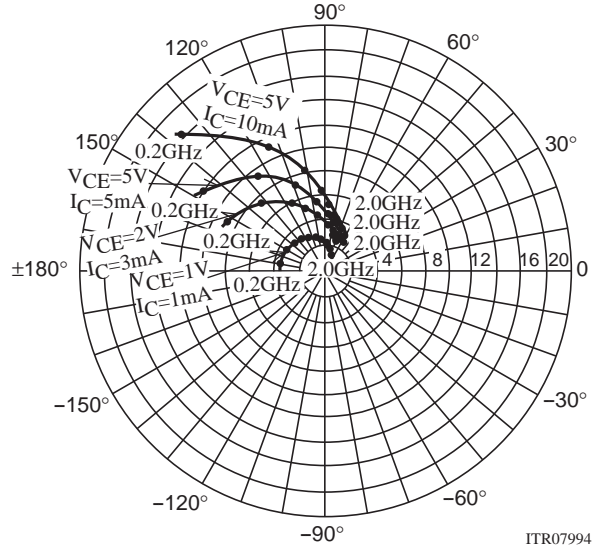
f=200MHz to 2000MHz(200MHz Step)



ITR07993

S21e

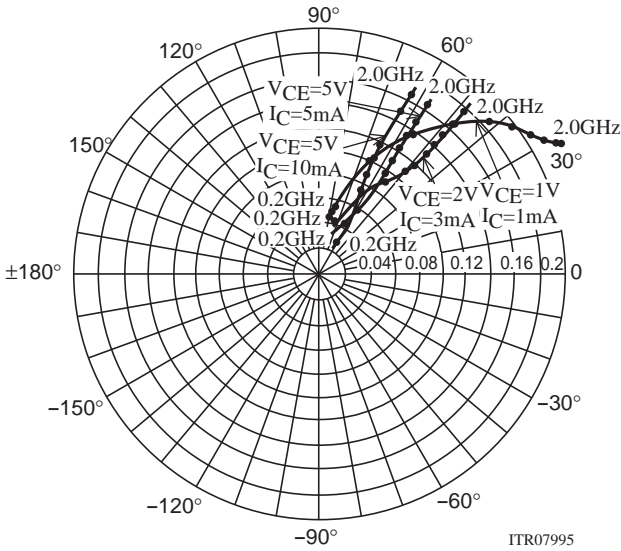
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ITR07994

S12e

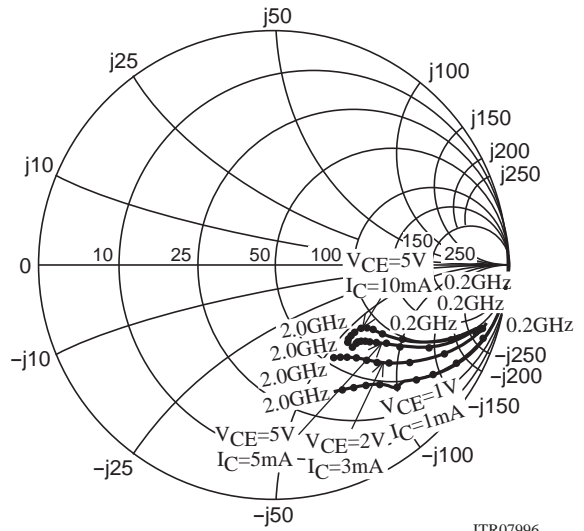
f=200MHz to 2000MHz(200MHz Step)



ITR07995

S22e

f=200MHz to 2000MHz(200MHz Step)



ITR07996

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S Parameters (Common emitter)

$V_{CE}=5V, I_C=5mA, Z_O=50\Omega$

Freq(MHz)	$ S_{11} $	$\angle S_{11}$	$ S_{21} $	$\angle S_{21}$	$ S_{12} $	$\angle S_{12}$	$ S_{22} $	$\angle S_{22}$
200	0.763	-37.5	11.926	146.9	0.036	70.7	0.892	-19.1
400	0.590	-65.4	9.202	124.3	0.058	60.9	0.740	-29.1
600	0.456	-85.5	7.173	109.4	0.073	57.4	0.631	-33.7
800	0.374	-102.0	5.743	98.7	0.086	56.7	0.566	-35.8
1000	0.323	-115.0	4.785	90.5	0.098	56.7	0.528	-37.2
1200	0.288	-127.5	4.105	83.6	0.110	57.2	0.505	-38.4
1400	0.264	-137.7	3.599	77.5	0.123	57.7	0.488	-39.6
1600	0.248	-147.4	3.213	71.3	0.136	57.6	0.476	-41.2
1800	0.239	-156.9	2.905	66.4	0.150	57.6	0.466	-43.3
2000	0.235	-165.7	2.651	61.3	0.165	57.2	0.462	-45.4

$V_{CE}=5V, I_C=10mA, Z_O=50\Omega$

Freq(MHz)	$ S_{11} $	$\angle S_{11}$	$ S_{21} $	$\angle S_{21}$	$ S_{12} $	$\angle S_{12}$	$ S_{22} $	$\angle S_{22}$
200	0.605	-52.6	16.354	136.2	0.031	67.5	0.804	-23.9
400	0.417	-84.6	11.011	113.3	0.048	62.4	0.622	-30.5
600	0.319	-106.3	8.026	100.5	0.062	62.2	0.533	-32.0
800	0.266	-124.6	6.250	91.3	0.076	63.4	0.491	-32.4
1000	0.238	-136.5	5.115	84.7	0.090	64.3	0.469	-33.2
1200	0.225	-148.9	4.336	78.8	0.104	64.4	0.458	-34.6
1400	0.215	-158.3	3.813	73.4	0.119	64.5	0.449	-35.8
1600	0.213	-167.3	3.365	68.1	0.135	63.8	0.443	-37.7
1800	0.212	-175.6	3.030	63.5	0.150	63.1	0.436	-39.6
2000	0.216	-177.5	2.754	58.9	0.166	62.5	0.438	-41.9

$V_{CE}=2V, I_C=3mA, Z_O=50\Omega$

Freq(MHz)	$ S_{11} $	$\angle S_{11}$	$ S_{21} $	$\angle S_{21}$	$ S_{12} $	$\angle S_{12}$	$ S_{22} $	$\angle S_{22}$
200	0.842	-30.7	8.491	153.0	0.044	72.5	0.931	-17.1
400	0.704	-56.3	7.161	131.9	0.075	60.9	0.808	-28.8
600	0.579	-76.1	5.879	116.3	0.095	54.1	0.696	-36.2
800	0.480	-93.1	4.882	104.2	0.109	51.0	0.615	-40.6
1000	0.417	-106.3	4.154	95.0	0.121	49.3	0.564	-43.5
1200	0.376	-119.6	3.597	87.1	0.132	48.7	0.526	-45.8
1400	0.343	-130.2	3.212	80.2	0.143	48.6	0.496	-47.5
1600	0.319	-140.5	2.875	73.4	0.154	48.7	0.475	-49.6
1800	0.303	-150.0	2.604	67.7	0.166	48.6	0.461	-51.6
2000	0.298	-160.0	2.383	62.1	0.179	48.9	0.451	-52.9

$V_{CE}=1V, I_C=1mA, Z_O=50\Omega$

Freq(MHz)	$ S_{11} $	$\angle S_{11}$	$ S_{21} $	$\angle S_{21}$	$ S_{12} $	$\angle S_{12}$	$ S_{22} $	$\angle S_{22}$
200	0.945	-18.9	3.296	162.5	0.054	77.2	0.980	-11.0
400	0.884	-37.3	3.206	145.9	0.102	65.9	0.934	-20.5
600	0.810	-53.6	2.942	131.2	0.139	56.3	0.870	-29.0
800	0.728	-69.4	2.711	117.8	0.166	48.6	0.811	-35.5
1000	0.667	-82.5	2.449	107.0	0.187	42.5	0.763	-40.9
1200	0.605	-95.8	2.252	96.9	0.199	37.3	0.715	-45.7
1400	0.561	-106.1	2.061	88.1	0.207	33.5	0.673	-49.4
1600	0.518	-117.2	1.909	79.5	0.212	30.6	0.638	-53.4
1800	0.492	-127.5	1.766	72.2	0.215	28.6	0.611	-56.5
2000	0.465	-137.9	1.658	65.2	0.217	27.6	0.592	-59.9

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